L # Type Hits Search Text DBs Time Stamp USPAT; US-PGP UB; EPO; (ONO or (oxide adj nitride 2003/12/16 JPO; BRS Ь1 1 87468 adj oxide)) DERWEN 10:08 Τ; IBM\_TD В USPAT; US-PGP UB; EPO; (gate near2 (insulat\$6 or 2003/12/16 BRS L285657 JPO; DERWEN 10:09 dielectric\$6)) Т; IBM TD USPAT; US-PGP UB; EPO: 1 near8 ((control\$6 or 2003/12/16 3 JPO; BRS L3 1478 DERWEN 10:10 float\$6) near2 gate)  $\mathbf{T}$ : IBM\_TD В USPAT; US-PGP UB: EPO; 2003/12/16 4 BRS JPO; L4 533 1 near4 2 DERWEN 10:12 T; IBM TD USPAT; US-PGP UB; EPO; 3 and (1 near4 (peripher\$6 2003/12/16 5 JPO; BRS L6 289 or memory)) DERWEN 10:13 Τ; IBM\_TD В

	Туре	L #	Hits	Search Text	DBs	Time Stamp
6	BRS	L5	244	3 and 4	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/16 10:14

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	Туре	L#	Hits	Search Text	DBs	Time Stamp
1	BRS	L353		((control\$6 or float\$6) near2 gate)) and ((ONO or oxide adj nitride adj	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/16 14:25
2	BRS	L354	244 ′	<pre>(((ONO or (oxide adj nitride adj oxide))) near8 nitride adj oxide))) near8 ((control\$6 or float\$6) near2 gate)) and (((ONO or (oxide adj nitride adj oxide))) near4 ((gate near2 (insulat\$6 or dielectric\$6))))</pre>	OLO,	2003/12/16 14:25
m .	BRS	L355	241	353 not 354	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/16

(periph\$4 on HV on high mean? volt\$4)

	Type	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L1	197871 7	memory or CAM or (code near2 address) or RAM or SRAM or flash	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD	2003/12/17 10:34
2	BRS	L2	8500	(gate near2 (insulator or dielectride))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 10:28
3	BRS	L6	87468	(ONO or (oxide adj nitride adj oxide))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 10:29
4	BRS	L7	85657	(gate near2 (insulat\$6 or dielectric\$6))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 10:29
5	BRS	L8	1478	((ONO or (oxide adj nitride adj oxide))) near8 ((control\$6 or float\$6) near2 gate)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17

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	Type	L #	Hits	Search Text	DBs	Time Stamp
10	BRS	L12	241	<pre>(oxide adj nitride adj oxide))) near4 (peripher\$6 or memory))) not (((ONO or (oxide adj nitride adj oxide))) near8 ((control\$6</pre>	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD	2003/12/17 10:29
11	BRS	L13	1137	(((ONO or O-N-O or (oxide near3 nitride near3 oxide))) near8 ((control\$6 or float\$6) near2 gate)) and (periph\$6 or HV or (high near2 volt\$6))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 10:34
12	BRS	L14	1125	13 and 1	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 10:34
13	BRS	L15	191	<pre>(((ONO or O-N-O or (oxide near3 nitride near3 oxide))) near8 ((control\$6 or float\$6) near2 gate)) same (periph\$6 or HV or (high near2 volt\$6))</pre>	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17

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	Туре	L #	Hits	Search Text	DBs	Time Stamp
1	BRS	L301	197871 7	memory or CAM or (code near2 address) or RAM or SRAM or flash	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 15:02
2	BRS	L302	8500	(gate near2 (insulator or dielectride))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 15:02
3	BRS	L303	87468	(ONO or (oxide adj nitride adj oxide))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 15:02
4	BRS	L304	85657	(gate near2 (insulat\$6 or dielectric\$6))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 15:02
5	BRS	L305	1478	((ONO or (oxide adj nitride adj oxide))) near8 ((control\$6 or float\$6) near2 gate)	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 15:02

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	Туре	L #	Hits	Search Text	DBs	Time Stamp
6	BRS	L306	533	((ONO or (oxide adj nitride adj oxide))) near4 ((gate near2 (insulat\$6 or dielectric\$6)))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 15:02
7	BRS	L307	289	((control\$6 or float\$6) near2 gate)) and (((ONO or (oxide adj nitride adj	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 15:02
8	BRS	L311	1137	(((ONO or O-N-O or (oxide near3 nitride near3 oxide))) near8 ((control\$6 or float\$6) near2 gate)) and (periph\$6 or HV or (high near2 volt\$6))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/17 15:03
9	BRS	L312	1125	oxide))) near8 ((control\$6 or float\$6) near2 gate)) and (periph\$6 or HV or (high near2 volt\$6))) and (memory or CAM or (code	US-PGP UB; EPO:	2003/12/17 15:03
10	BRS	L308	15	near2 (insulator or dielectride))) same (memory	UB; EPO; JPO; DERWEN	2003/12/17 15:03

	Туре	L #	Hits	Search Text	DBs	Time Sta
11	BRS	L309	244	<pre>(((ONO or (oxide adj nitride adj oxide))) near8 ((control\$6 or float\$6) near2 gate)) and (((ONO or (oxide adj nitride adj oxide))) near4 ((gate near2 (insulat\$6 or dielectric\$6))))</pre>	DEDWEN	2003/12/1 15:03
12	BRS	L310	241	<pre>((((ONO or (oxide adj nitride adj oxide))) near8 ((control\$6 or float\$6) near2 gate)) and ((ONO or (oxide adj nitride adj oxide))) near4 (peripher\$6 or memory))) not (((ONO or (oxide adj nitride adj oxide))) near8 ((control\$6 or float\$6) near2 gate)) and ((ONO or (oxide adj nitride adj oxide))) near4 ((gate near2 (insulat\$6 or dielectric\$6)))))</pre>	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/: 15:03
13	BRS	L313	191	(((ONO or O-N-O or (oxide near3 nitride near3 oxide))) near8 ((control\$6 or float\$6) near2 gate)) same (periph\$6 or HV or (high near2 volt\$6))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/1 15:08
14	BRS	L314	245	(ONO or O-N-O or (oxide near3 nitride near3 oxide)) near4 (periph\$6 or HV or (high near2 volt\$6))	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B	2003/12/1 15:10

	Туре	L #	Hits	Search Text	DBs
1	IS&Ř	L1	161	(438/142).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
2	IS&R	L2	201	(438/263).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
3	IS&R	Ľ3	614	(438/258).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
4	IS&R	L4	1476	(438/257).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
5	IS&R	L5	170	(438/211).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B

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	Туре	L #	Hits	Search Text	DBs
6	IS&R	L6	507	(150, 750, 75025.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B
7	IS&R	<b>L</b> 7	143	(438/757).CCLS.	USPAT; US-PGP UB; EPO; JPO; DERWEN T; IBM_TD B

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